

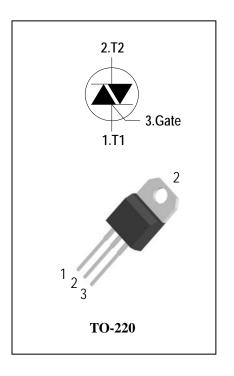
3 Quadrants High temperature Triacs

General Description

High current density due to mesa technology , guaranteed maximum junction temperature 150° C. The ADS8CH triac series is suitable for general purpose AC switching. They can beused as an ON/OFF function in applications such as static relays, heating regulation, High power motor controls e.g. washing machines and vacuum cleaners,Rectifier-fed DC inductive loads e.g.DC motors and solenoids , motor speed controllers. The heatsink can be reduced,compared to traditional triacs, according to the high performance at given junction temperatures.

Features

- ◆ Repetitive Peak Off-State Voltage: 600V/800V
- ◆ R.M.S On-State Current (IT(RMS)= 8A)
- ◆ High Commutation dv/dt
- ◆ High junction temperature operating capability
- ◆ These Devices are Pb-Free and are RoHS Compliant



Absolute Maximum Ratings

Symbol	Items	Conditions		Ratings	Unit
V_{DRM}	Denetitive Deals Off Chate Veltage	T: - 25°C	ADS8CH60	600	V
V_{RRM}	Repetitive Peak Off-State Voltage	Tj = 25°C	ADS8CH80	800	V
I _{T(RMS)}	R.M.S On-State Current	T _C = 135 °C		8	Α
I _{TSM}	Surge On-State Current	tp=20ms(50Hz)/tp=16.7ms(60Hz)		80/84	А
l ² t	I ² t for fusing	tp=10ms		36	A ² s
-11/-14	Critical rate of rise of on-state F = 120 Hz Tj = 150°C		50	A / .	
dI/dt	current	$I_G = 2 \times I_{GT}$, tr $\leq 100 \text{ ns}$	50	A/µs	
I _{GM}	Peak Gate Current	tp = 20 μs Tj = 150°C		4	Α
$P_{G(AV)}$	Average Gate Power Dissipation(Tj=150°C)			1	W
P_GM	Peak Gate Power Dissipation(tp=20us,Tj=150°C)			10	W
T _j	Operating Junction Temperature			- 40 ~ 150	°C
T _{STG}	Storage Temperature			- 40 ~ 150	°C



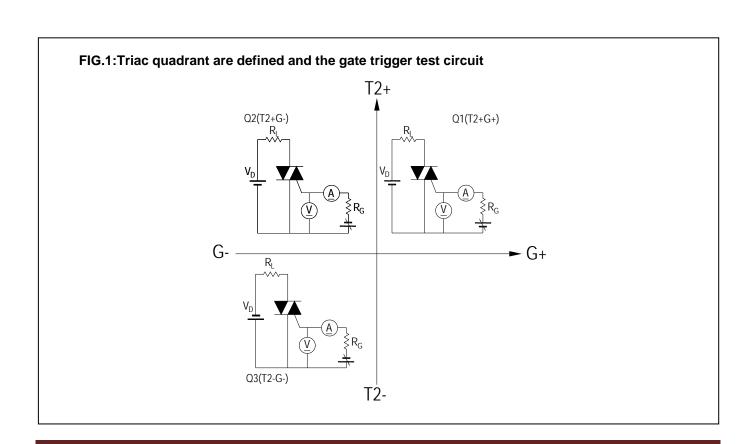


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Electrical Characteristics(Tj = 25°C unless otherwise specified)

Symbol	Items		Conditions		ADS8CH60/80			Unit
					S	Blank	В	
I _{DRM}	Peak Forward Reverse Blocking		$V_{DRM} = V_{RRM}$, $Tj = 25$ °C	May	5		uA	
I _{RRM}	Current		$V_{DRM} = V_{RRM}$, $Tj = 150$ °C	Max.	2.5		mA	
V_{TM}	Peak On-S	tate Voltage	I _{TM} = 11A, t _p = 380 μs	Max.	1.5			V
V_{GD}	Q1-Q2-Q3	Non-Trigger Gate Voltage	$V_D = V_{DRM}$ $R_L = 3.3 \text{ k}\Omega$ $Tj = 150^{\circ}\text{C}$	Min.	0.2		>	
V_{GT}	Q1-Q2-Q3	Gate Trigger Voltage	V 40V D 200	Max.	1.5		٧	
I _{GT}	Q1-Q2-Q3	Gate Trigger Current	$V_D = 12V$, $R_L = 33\Omega$	Max.	10	35	50	mA
I _H	Q1-Q2-Q3	Holding Current	I _T = 0.1A	Max.	20	45	60	mA
ΙL	Q1-Q3	Latabina Cumant	Current $I_G = 1.2 I_{GT}$ Max.	Mov	20	50	70	m A
	Q2	Latching Current		35	70	100	mA	
dV/dt	Critical Rate of Rise of Off-State Voltage		$V_D = 2/3V_{DRM}$ gate open Tj = 150°C	Min.	200	1000	1500	V/µs
(dV/dt)c	Critical Rate of Change of Commutating Voltage		V_D =400V Tj = 150°C (dl/dt)c=3.5A/ms	Min.	1	15	20	V/µs
R _{th(j-c)}	Junction to case (AC)		Max.	1.85		°C/W		
R _{th(j-a)}	Junction to ambient			Max.	60			°C/W



ADV

FIG.2: Maximum on-state power dissipation

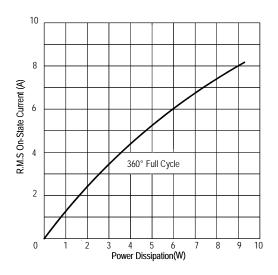


FIG.4: Maximum transient thermal impedance

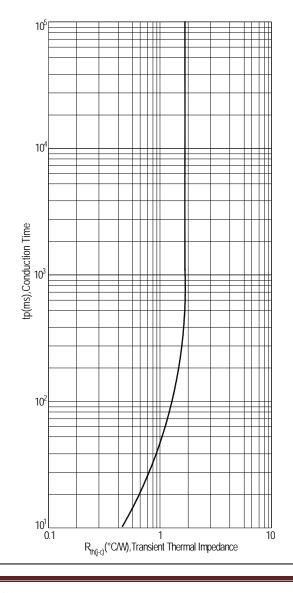


FIG.3: Typical RMS on-state current VS Allowable case Temperature

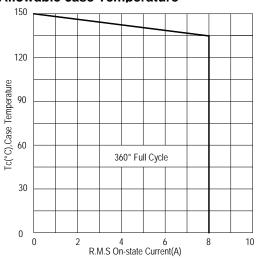


FIG.5: Rated surge on-state current (Non-Repetitive)

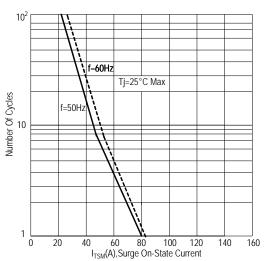


FIG.6: Gate trigger current VS Junction temperature

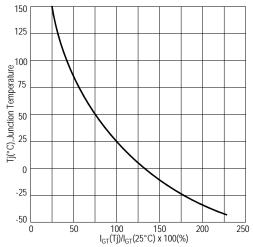




FIG.7:Holding current and Latching current VS Junction temperature

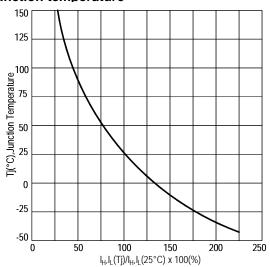


FIG.8: Gate trigger voltage VS Junction temperature

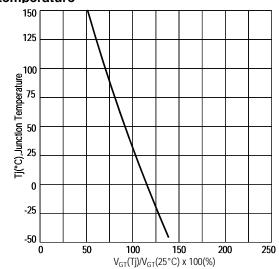
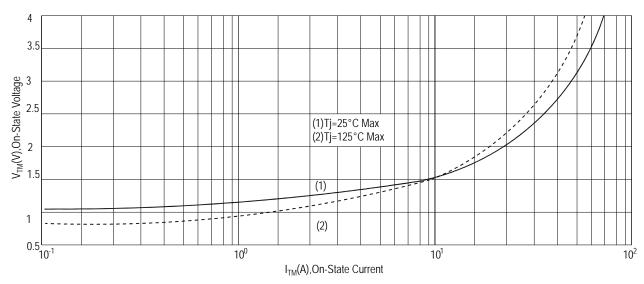


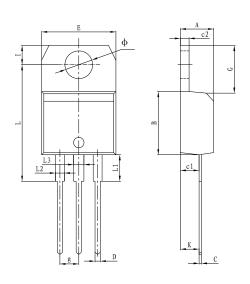
FIG.9: On-state characteristics(Max)



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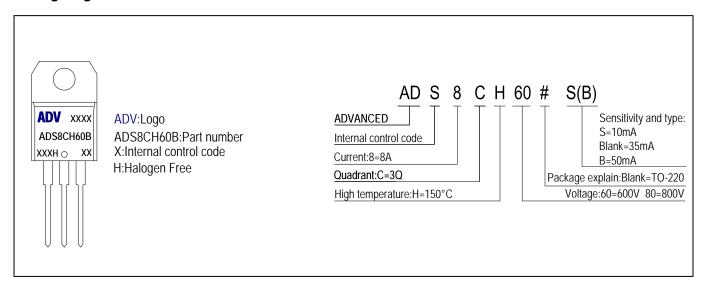


PACKAGE MECHANICAL DATA TO-220 Package Dimension



	Dimer	sions	Dimensions			
Symbol	In Millimeters		In Inches			
	Min	Max	Min	Max		
Α	4.40	4.60	0.173	0.181		
В	9.00	9.30	0.354	0.366		
С	0.40	0.60	0.015	0.023		
c1	2.00	2.60	0.078	0.102		
c2	1.23	1.32	0.048	0.051		
D	0.70	1.00	0.027	0.039		
E	10.00	10.40	0.393	0.409		
g	2.40	2.70	0.094	0.106		
G	6.20	6.80	0.244	0.267		
I	2.65	2.95	0.104	0.116		
L	15.80	16.80	0.622	0.661		
L1	3.75		0.147			
L2	1.14	1.70	0.044	0.066		
L3	1.14	1.70	0.044	0.066		
Ф	3.60	3.90	0.141	0.153		
K	2.60	TYP	0.102TYP			

Making Diagram



Ordering information

Part number	Package	Marking	Packing	Quantity		
ADS8CH60#	TO-220	ADS8CH60#	Tube	50pcs		
ADS8CH80#	TO-220	ADS8CH80#	Tube	50pcs		
Note:# = Gate Trigger Current Sensitivity and type						



ADS8CH60/80

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